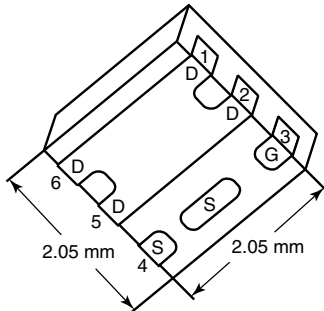


P-Channel 20 V (D-S) MOSFET

| PRODUCT SUMMARY | | | |
|---------------------|-------------------------------------|---------------------------------|-----------------------|
| V _{DS} (V) | R _{DS(on)} (Ω) (Max.) | I _D (A) ^a | Q _g (Typ.) |
| - 20 | 0.0350 at V _{GS} = - 4.5 V | - 9 | 10 nC |
| | 0.0395 at V _{GS} = - 3.7 V | - 9 | |
| | 0.0620 at V _{GS} = - 2.5 V | - 9 | |

PowerPAK SC-70-6L-Single

Ordering Information:

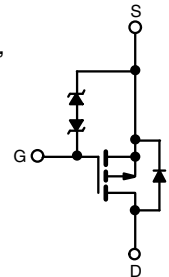
SiA459EDJ-T1-GE3 (Lead (Pb)-free and Halogen-free)

FEATURES

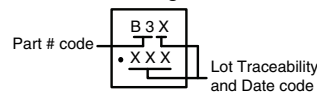
- TrenchFET[®] Power MOSFET
- Thermally Enhanced PowerPAK[®] SC-70 Package
 - Small Footprint Area
 - Low On-Resistance
- 100 % R_g Tested
- Typical ESD Protection: 2000 V (HBM)
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912


RoHS
 COMPLIANT
 HALOGEN
FREE
APPLICATIONS

- Portable Devices such as Smart Phones, Tablet PCs and Mobile Computing
 - DC/DC Converter
 - Battery Switch
 - Load Switch
 - Power Management



P-Channel MOSFET

Marking Code


| ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted) | | | | |
|---|-----------------------------------|------------------------|-----------------------|---|
| Parameter | Symbol | Limit | Unit | |
| Drain-Source Voltage | V _{DS} | - 20 | V | |
| Gate-Source Voltage | V _{GS} | ± 12 | | |
| Continuous Drain Current (T _J = 150 °C) | I _D | T _C = 25 °C | - 9 ^a | A |
| | | T _C = 70 °C | - 9 ^a | |
| | | T _A = 25 °C | - 7.4 ^{b, c} | |
| | | T _A = 70 °C | - 6 ^{b, c} | |
| Pulsed Drain Current (t = 100 μs) | I _{DM} | - 40 | | |
| Continuous Source-Drain Diode Current | I _S | T _C = 25 °C | - 9 ^a | |
| | | T _A = 25 °C | - 2.4 ^{b, c} | |
| Maximum Power Dissipation | P _D | T _C = 25 °C | 15.6 | W |
| | | T _C = 70 °C | 10 | |
| | | T _A = 25 °C | 2.9 ^{b, c} | |
| | | T _A = 70 °C | 1.8 ^{b, c} | |
| Operating Junction and Storage Temperature Range | T _J , T _{stg} | - 50 to 150 | °C | |
| Soldering Recommendations (Peak Temperature) ^{d, e} | | 260 | | |

| THERMAL RESISTANCE RATINGS | | | | | |
|---|--------------|-------------------|---------|---------|------|
| Parameter | | Symbol | Typical | Maximum | Unit |
| Maximum Junction-to-Ambient ^{b, f} | t ≤ 5 s | R _{thJA} | 32 | 43 | °C/W |
| Maximum Junction-to-Case (Drain) | Steady State | R _{thJC} | 6 | 8 | |

Notes

- Package limited.
- Surface mounted on 1" x 1" FR4 board.
- t = 5 s.
- See solder profile (www.vishay.com/doc?73257). The PowerPAK SC-70 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.
- Maximum under steady state conditions is 80 °C/W.



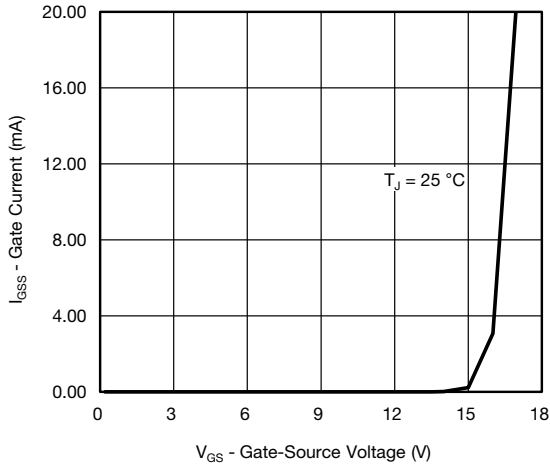
| SPECIFICATIONS (T _J = 25 °C, unless otherwise noted) | | | | | | |
|---|--------------------------------------|---|-------|--------|--------|-------|
| Parameter | Symbol | Test Conditions | Min. | Typ. | Max. | Unit |
| Static | | | | | | |
| Drain-Source Breakdown Voltage | V _{DS} | V _{GS} = 0 V, I _D = - 250 μA | - 20 | | | V |
| V _{DS} Temperature Coefficient | ΔV _{DS} /T _J | I _D = - 250 μA | | - 12 | | mV/°C |
| V _{GS(th)} Temperature Coefficient | ΔV _{GS(th)} /T _J | | | 2.2 | | |
| Gate-Source Threshold Voltage | V _{GS(th)} | V _{DS} = V _{GS} , I _D = - 250 μA | - 0.6 | | - 1.2 | V |
| Gate-Source Leakage | I _{GSS} | V _{DS} = 0 V, V _{GS} = ± 12 V | | | ± 10 | μA |
| | | V _{DS} = 0 V, V _{GS} = ± 4.5 V | | | ± 0.5 | |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} = - 20 V, V _{GS} = 0 V | | | - 1 | |
| | | V _{DS} = - 20 V, V _{GS} = 0 V, T _J = 55 °C | | | - 10 | |
| On-State Drain Current ^a | I _{D(on)} | V _{DS} ≤ - 5 V, V _{GS} = - 4.5 V | - 10 | | | A |
| Drain-Source On-State Resistance ^a | R _{DS(on)} | V _{GS} = - 4.5 V, I _D = - 5 A | | 0.0280 | 0.0350 | Ω |
| | | V _{GS} = - 3.7 V, I _D = - 5 A | | 0.0310 | 0.0395 | |
| | | V _{GS} = - 2.5 V, I _D = - 2 A | | 0.0450 | 0.0620 | |
| Forward Transconductance ^a | g _{fs} | V _{GS} = - 10 V, I _D = - 5 A | | 15 | | S |
| Dynamic^b | | | | | | |
| Input Capacitance | C _{iss} | V _{DS} = - 10 V, V _{GS} = 0 V, f = 1 MHz | | 885 | | pF |
| Output Capacitance | C _{oss} | | | 155 | | |
| Reverse Transfer Capacitance | C _{rss} | | | 140 | | |
| Total Gate Charge | Q _g | V _{DS} = - 10 V, V _{GS} = - 10 V, I _D = - 5 A | | 20 | 30 | nC |
| | | V _{DS} = - 10 V, V _{GS} = - 4.5 V, I _D = - 5 A | | 10 | 15 | |
| Gate-Source Charge | Q _{gs} | | | 1.6 | | |
| Gate-Drain Charge | Q _{gd} | | | 2.9 | | |
| Gate Resistance | R _g | f = 1 MHz | 2.2 | 11 | 22 | Ω |
| Turn-On Delay Time | t _{d(on)} | V _{DD} = - 10 V, R _L = 1.67 Ω I _D ≅ - 6 A, V _{GEN} = - 4.5 V, R _g = 1 Ω | | 20 | 40 | ns |
| Rise Time | t _r | | | 25 | 50 | |
| Turn-Off Delay Time | t _{d(off)} | | | 40 | 80 | |
| Fall Time | t _f | | | 20 | 40 | |
| Turn-On Delay Time | t _{d(on)} | V _{DD} = - 10 V, R _L = 1.67 Ω I _D ≅ - 6 A, V _{GEN} = - 10 V, R _g = 1 Ω | | 7 | 15 | |
| Rise Time | t _r | | | 10 | 20 | |
| Turn-Off Delay Time | t _{d(off)} | | | 40 | 80 | |
| Fall Time | t _f | | | 20 | 40 | |
| Drain-Source Body Diode Characteristics | | | | | | |
| Continuous Source-Drain Diode Current | I _S | T _C = 25 °C | | | - 9 | A |
| Pulse Diode Forward Current | I _{SM} | | | | - 40 | |
| Body Diode Voltage | V _{SD} | I _S = - 6 A, V _{GS} = 0 V | | - 0.9 | - 1.2 | V |
| Body Diode Reverse Recovery Time | t _{rr} | I _F = - 6 A, di/dt = 100 A/μs, T _J = 25 °C | | 21 | 35 | ns |
| Body Diode Reverse Recovery Charge | Q _{rr} | | | 9 | 20 | nC |
| Reverse Recovery Fall Time | t _a | | | 7 | | ns |
| Reverse Recovery Rise Time | t _b | | | 14 | | |

Notes

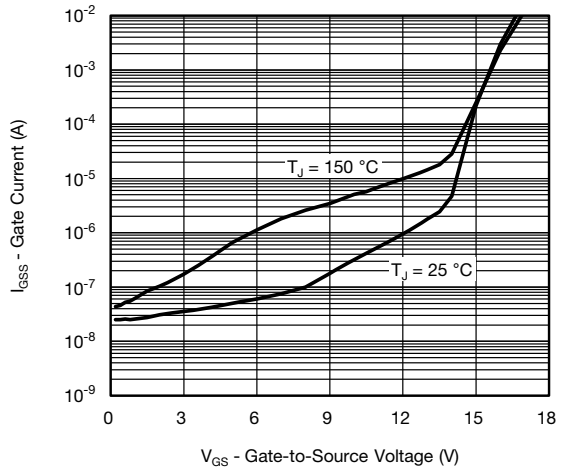
- a. Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

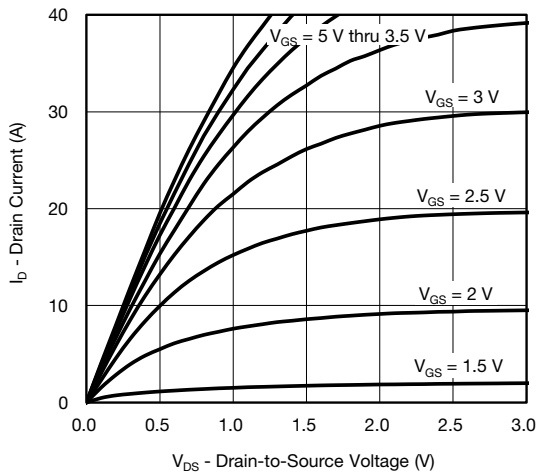
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



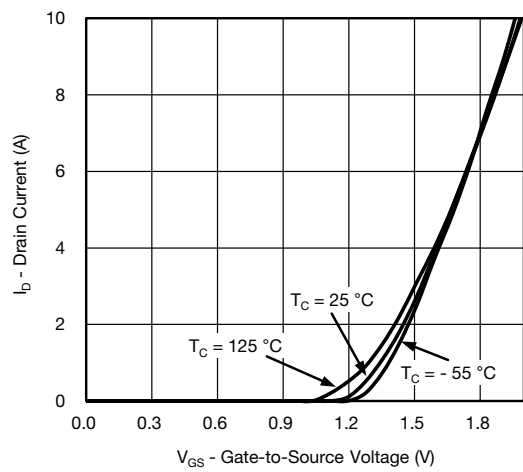
Gate Current vs. Gate-Source Voltage



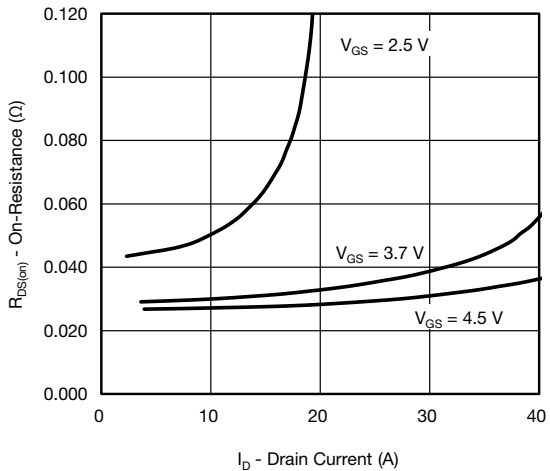
Gate Current vs. Gate-to-Source Voltage



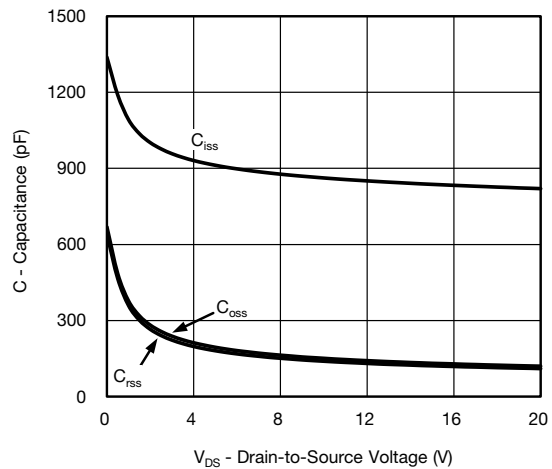
Output Characteristics



Transfer Characteristics



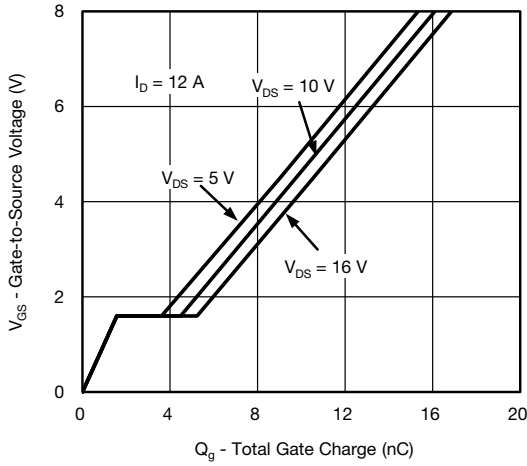
On-Resistance vs. Drain Current and Gate Voltage



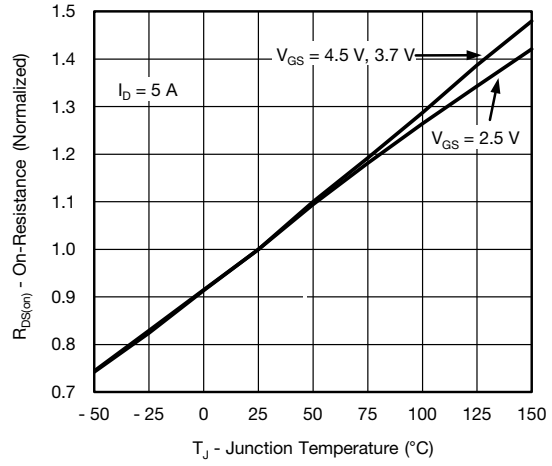
Capacitance



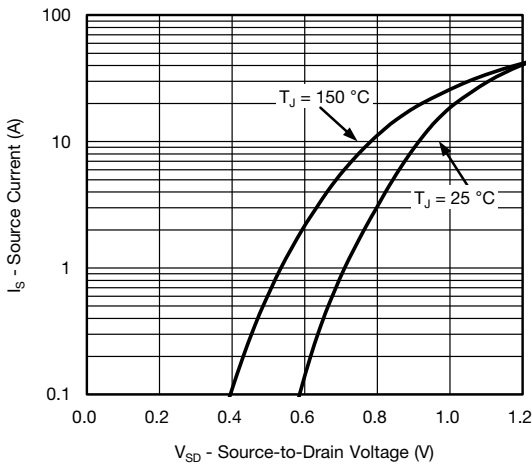
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



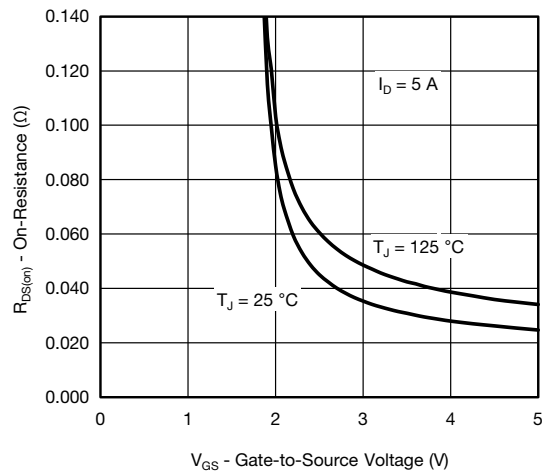
Gate Charge



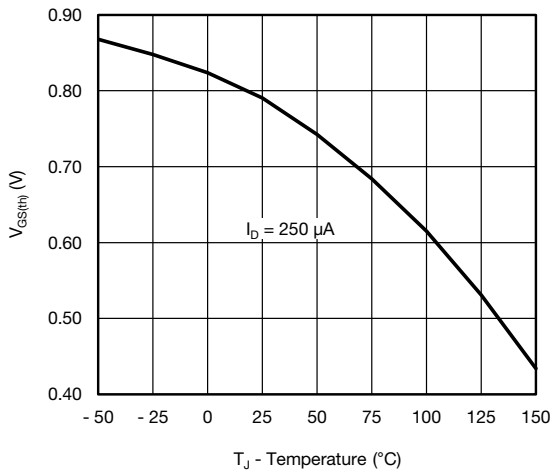
On-Resistance vs. Junction Temperature



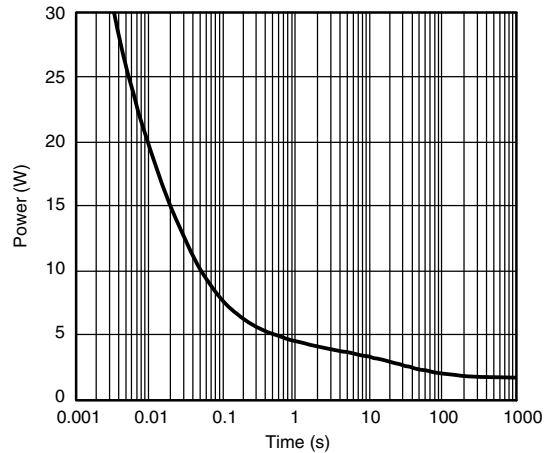
Source-Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage



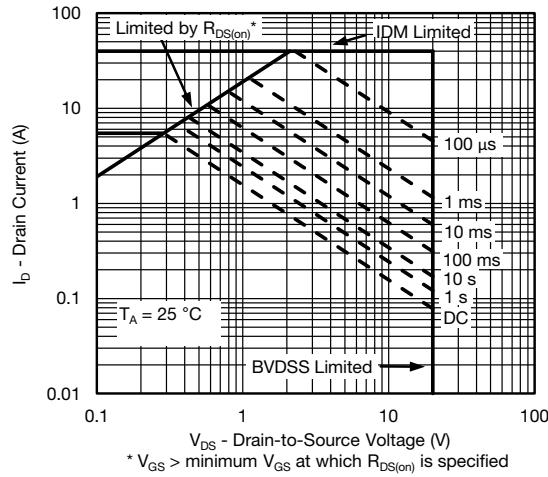
Threshold Voltage



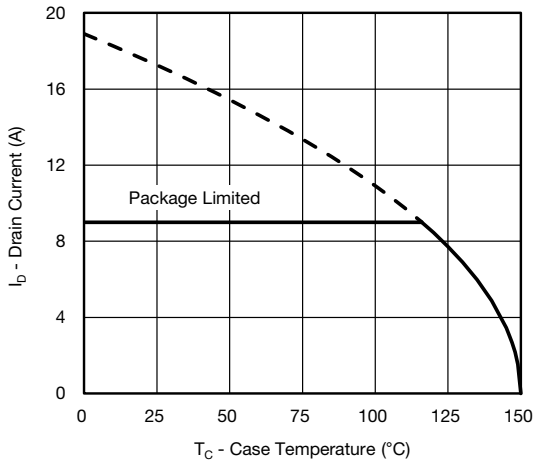
Single Pulse Power, Junction-to-Ambient



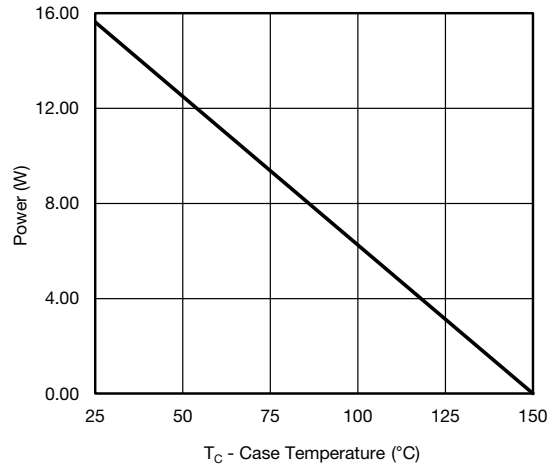
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Safe Operating Area, Junction-to-Ambient



Current Derating*

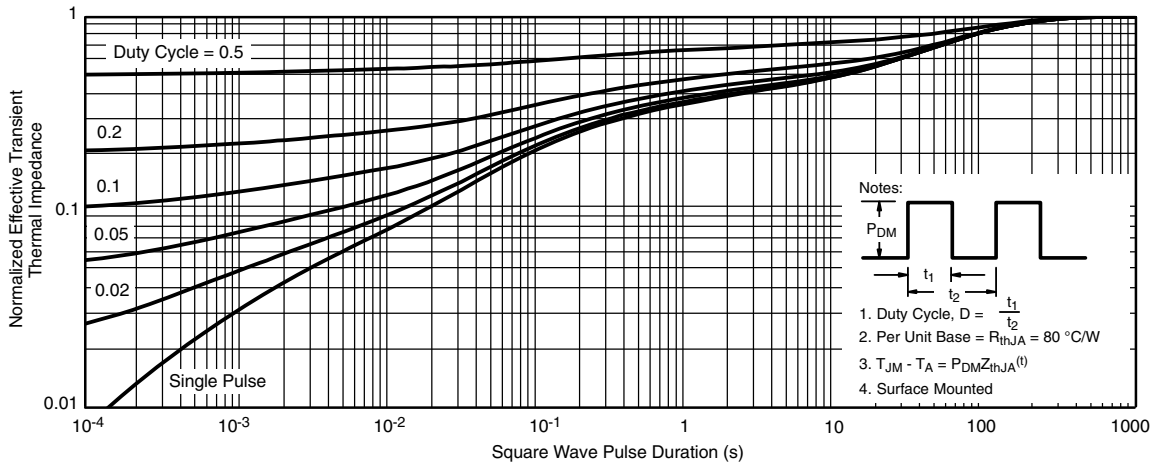


Power Derating

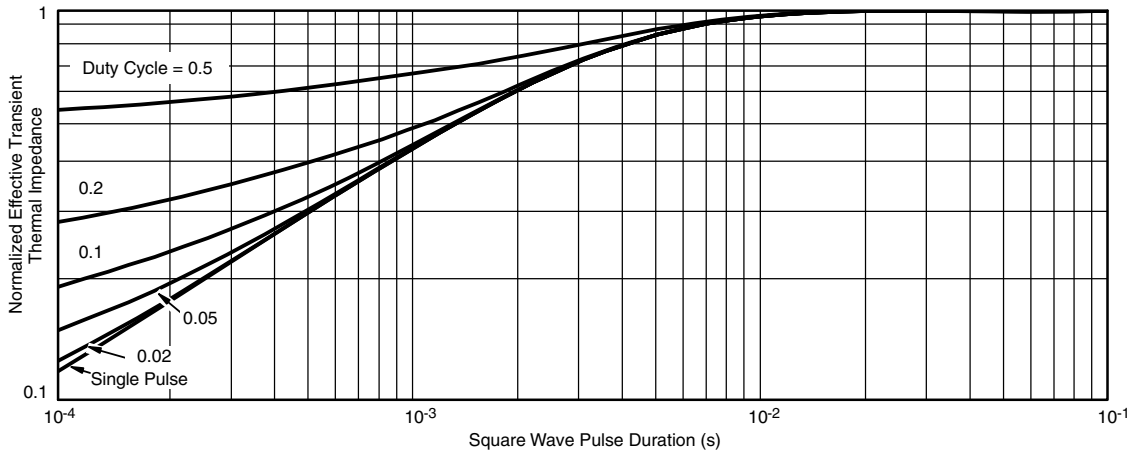
* The power dissipation P_D is based on $T_{J(max.)} = 150\text{ }^\circ\text{C}$, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?62912.



PowerPAK® SC70-6L



BACKSIDE VIEW OF SINGLE



BACKSIDE VIEW OF DUAL



- Notes:
 1. All dimensions are in millimeters
 2. Package outline exclusive of mold flash and metal burr
 3. Package outline inclusive of plating

| DIM | SINGLE PAD | | | | | | DUAL PAD | | | | | |
|-----|-------------|-------|-------|-----------|-------|-------|-------------|-------|-------|-----------|-------|-------|
| | MILLIMETERS | | | INCHES | | | MILLIMETERS | | | INCHES | | |
| | Min | Nom | Max | Min | Nom | Max | Min | Nom | Max | Min | Nom | Max |
| A | 0.675 | 0.75 | 0.80 | 0.027 | 0.030 | 0.032 | 0.675 | 0.75 | 0.80 | 0.027 | 0.030 | 0.032 |
| A1 | 0 | - | 0.05 | 0 | - | 0.002 | 0 | - | 0.05 | 0 | - | 0.002 |
| b | 0.23 | 0.30 | 0.38 | 0.009 | 0.012 | 0.015 | 0.23 | 0.30 | 0.38 | 0.009 | 0.012 | 0.015 |
| C | 0.15 | 0.20 | 0.25 | 0.006 | 0.008 | 0.010 | 0.15 | 0.20 | 0.25 | 0.006 | 0.008 | 0.010 |
| D | 1.98 | 2.05 | 2.15 | 0.078 | 0.081 | 0.085 | 1.98 | 2.05 | 2.15 | 0.078 | 0.081 | 0.085 |
| D1 | 0.85 | 0.95 | 1.05 | 0.033 | 0.037 | 0.041 | 0.513 | 0.613 | 0.713 | 0.020 | 0.024 | 0.028 |
| D2 | 0.135 | 0.235 | 0.335 | 0.005 | 0.009 | 0.013 | | | | | | |
| E | 1.98 | 2.05 | 2.15 | 0.078 | 0.081 | 0.085 | 1.98 | 2.05 | 2.15 | 0.078 | 0.081 | 0.085 |
| E1 | 1.40 | 1.50 | 1.60 | 0.055 | 0.059 | 0.063 | 0.85 | 0.95 | 1.05 | 0.033 | 0.037 | 0.041 |
| E2 | 0.345 | 0.395 | 0.445 | 0.014 | 0.016 | 0.018 | | | | | | |
| E3 | 0.425 | 0.475 | 0.525 | 0.017 | 0.019 | 0.021 | | | | | | |
| e | 0.65 BSC | | | 0.026 BSC | | | 0.65 BSC | | | 0.026 BSC | | |
| K | 0.275 TYP | | | 0.011 TYP | | | 0.275 TYP | | | 0.011 TYP | | |
| K1 | 0.400 TYP | | | 0.016 TYP | | | 0.320 TYP | | | 0.013 TYP | | |
| K2 | 0.240 TYP | | | 0.009 TYP | | | 0.252 TYP | | | 0.010 TYP | | |
| K3 | 0.225 TYP | | | 0.009 TYP | | | | | | | | |
| K4 | 0.355 TYP | | | 0.014 TYP | | | | | | | | |
| L | 0.175 | 0.275 | 0.375 | 0.007 | 0.011 | 0.015 | 0.175 | 0.275 | 0.375 | 0.007 | 0.011 | 0.015 |
| T | | | | | | | 0.05 | 0.10 | 0.15 | 0.002 | 0.004 | 0.006 |

ECN: C-07431 – Rev. C, 06-Aug-07
 DWG: 5934

RECOMMENDED PAD LAYOUT FOR PowerPAK® SC70-6L Single



Dimensions in mm/(Inches)

[Return to Index](#)



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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

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- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

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